6 Line EMI Filter with ESD Protection

This device is a 6 line EMI filter array for wireless applications. Greater than -30 dB attenuation is obtained at frequencies from $800 \, \text{MHz}$ to $2.4 \, \text{GHz}$. It also offers ESD protection clamping transients from static discharges. ESD protection is provided across all capacitors.

Features

- EMI Filtering and ESD Protection
- Integration of 30 Discrete Components
- DFN Package, 1.35 x 3.0 mm
- Moisture Sensitivity Level 1
- ESD Ratings: IEC61000-4-2 (Level 4)

Machine Model = C Human Body Model = 3B

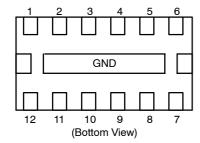
• This is a Pb-Free Device

Benefits

- Reduces EMI/RFI Emissions on a Data Line
- Integrated Solution Offers Cost and Space Savings in a DFN Package
- Excellent S21 Characteristics with very Low Parasitic Inductances
- Integrated Solution Improves System Reliability
- Compatible Footprint to BGA or Flip-Chip Package

Applications

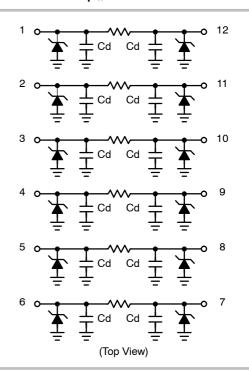
- EMI Filtering and ESD Protection for Data Lines
- Wireless Phones
- PDAs and Handheld Products
- Digital Camera
- LCD Displays





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http://onsemi.com



MARKING DIAGRAM



1

DFN12 CASE 506AD



6400= Specific Device Code

 $\overline{M} = Month$

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NUF6400MNTBG	DFN12 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

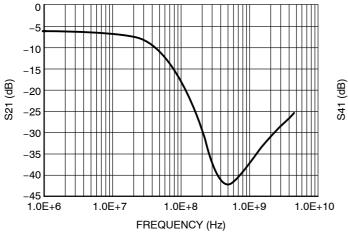
Parameter	Symbol	Value	Unit
ESD Discharge IEC61000-4-2 Contact Discharge	V_{PP}	8.0	kV
DC Power per Resistor	P _R	100	mW
DC Power per Package	P _T	600	mW
Operating Temperature Range	T _{OP}	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C
Maximum Lead Temperature for Soldering Purposes (1.8 in from case for 10 seconds)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Maximum Reverse Working Voltage	V_{RWM}				5.0	V
Breakdown Voltage	V_{BR}	I _R = 1.0 mA	6.0	7.0		V
Leakage Current	I _R	V _{RWM} = 3.0 V			0.1	μΑ
Resistance	R _A	I _R = 20 mA	85	100	115	Ω
Capacitance (Notes 1 and 2)	C _d	V _R = 2.5 V, f = 1.0 MHz		50	75	pF
Cut-Off Frequency (Note 3)	f _{3dB}	Above this frequency, appreciable attenuation occurs		35		MHz

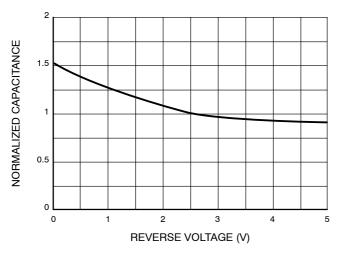
- Measured at 25°C, V_R = 2.5 V, f = 1.0 MHz.
 Total line capacitance is 2 times the Diode Capacitance (Cd).
- 3. $50~\Omega$ source and $50~\Omega$ load termination.



0 -10 -20 -30 -40 -50 -60 -70 -80 10E+6 100E+6 1.0E+9 10E+9 FREQUENCY (Hz)

Figure 1. Typical Insertion Loss Characteristic

Figure 2. Typical Analog Crosstalk



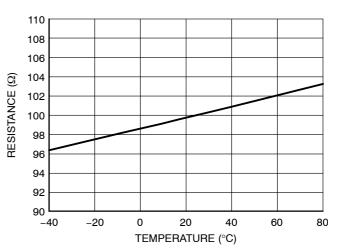
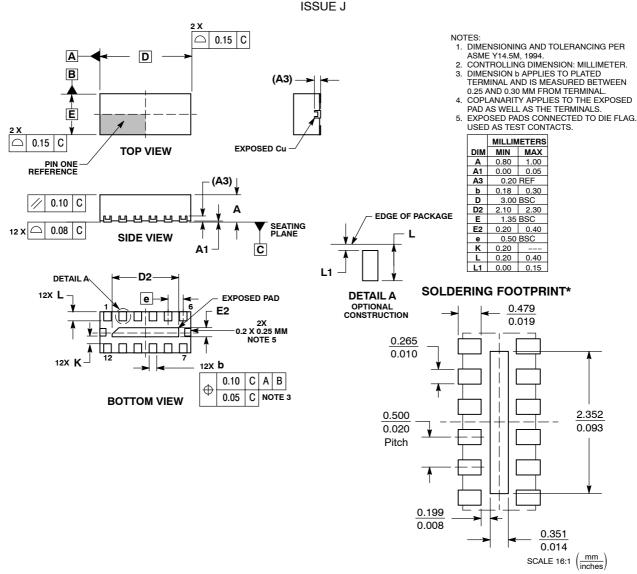


Figure 3. Typical Capacitance vs.
Reverse Biased Voltage
(Normalized Capacitance, Cd @ 2.5 V)

Figure 4. Typical Resistance over Temperature

PACKAGE DIMENSIONS

DFN12 3.0x1.35, 0.5P CASE 506AD-01



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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